

Sum and Difference Amplifier Modules

Position Sensing Modules

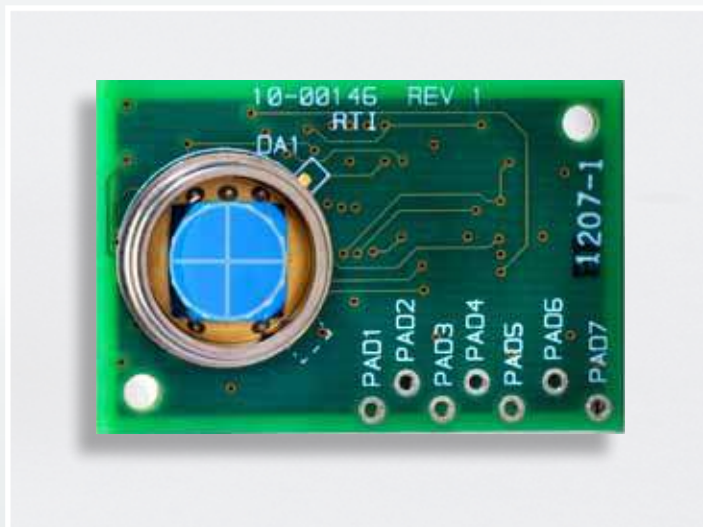
QD7-0-SD or **QD50-0-SD** are quadrant photodiode arrays with associated circuitry to provide two difference signals and a sum signal. The two difference signals are voltage analogs of the relative intensity difference of the light sensed by opposing pairs of the photodiode quadrant elements. In addition the amplified sum of all 4 quadrant elements is provided as the sum signal. This makes the QD7-0-SD or QD50-0-SD ideal for both light beam nulling and position applications. Very precise light beam alignments are possible, and the circuit can also be used for target acquisition and alignment.

APPLICATIONS

- Position Measuring
- Beam Centering
- Targeting
- Guidance Systems

FEATURES

- Other QD7-XX or QD50-XX are available upon request



Values given as per element unless otherwise stated

Model Number	Active Area Total		Element Gap (mm)	Responsivity (A/W)		Capacitance (pF)	Dark Current (nA)		NEP (W/√Hz)	Reverse Voltage (V)	Rise Time (ns)	Temp Range (°C)		Package Style ¶				
	Area (mm²)	Dimensions (mm)		900 nm			0 V	0 V				900 nm	-30 V		900 nm	50 Ω	Operating	Storage
				min.	typ.													
'O' Series																		
QD7-0	7	3.0 ϕ	0.2	0.47	0.54	20	4.0	15.0	9.0 e-14	30	10	-40 ~ +100	-55 ~ +125	41 / TO-5				
QD50-0	50	8.0 ϕ												125	15.0	30.0	1.3 e-13	70 / TO-8

INPUT

Power supply voltage $V_{CC} = \pm 4.5V$ min; $\pm 15V$ typical; $\pm 18V$ max

Photodiode bias voltage = $(.91) \times (V_{PDBIAS})$

$V_{PDBIAS} = 0$ TO $+V_{CC}$; Absolute maximum V_{PDBIAS} is $+V_{CC}$

NOTE: Negative voltages applied to PDBIAS will render the QD7-0-SD or QD50-0-SD inoperative.

ENVIRONMENTAL

Operating temperature	0 to 70° C
Theoretical noise	15 nV/Hz ^{1/2}
Frequency response	(-3dB): 120kHz @ $V_{PDBIAS}=0V$; 880nm 250kHz @ $V_{PDBIAS}=15V$; 880nm
Max slew rate	10V/μs
Output current limit	25 mA

OUTPUT

Where i_x is the current from quadrant x

$$V_{T-B} = -\{(i_1 + i_2) - (i_3 + i_4)\} \times (10^4)$$

$$V_{L-R} = -\{(i_2 + i_3) - (i_1 + i_4)\} \times (10^4)$$

$$V_{SUM} = -\{(i_1 + i_2 + i_3 + i_4)\} \times (10^4)$$

MAXIMUM OUTPUT VOLTAGE

Positive: $(+V_{CC} - 3V)$

Negative: $(-V_{CC} + 3V)$

AVOID DIRECT LIGHT

Since the spectral response of silicon photodiode includes the visible light region, care must be taken to avoid photodiode exposure to high ambient light levels, particularly from tungsten sources or sunlight. During shipment from OSI Optoelectronics, your photodiodes are packaged in opaque, padded containers to avoid ambient light exposure and damage due to shock from dropping or jarring.

AVOID SHARP PHYSICAL SHOCK

Photodiodes can be rendered inoperable if dropped or sharply jarred. The wire bonds are delicate and can become separated from the photodiode's bonding pads when the detector is dropped or otherwise receives a sharp physical blow.

CLEAN WINDOWS WITH OPTICAL GRADE CLOTH / TISSUE

Most windows on OSI Optoelectronics photodiodes are either silicon or quartz. They should be cleaned with isopropyl alcohol and a soft (optical grade) pad.

OBSERVE STORAGE TEMPERATURES AND HUMIDITY LEVELS

Photodiode exposure to extreme high or low storage temperatures can affect the subsequent performance of a silicon photodiode. Storage temperature guidelines are presented in the photodiode performance specifications of this catalog. Please maintain a non-condensing environment for optimum performance and lifetime.

OBSERVE ELECTROSTATIC DISCHARGE (ESD) PRECAUTIONS

OSI Optoelectronics photodiodes, especially with IC devices (e.g. Photops) are considered ESD sensitive. The photodiodes are shipped in ESD protective packaging. When unpacking and using these products, anti-ESD precautions should be observed.

DO NOT EXPOSE PHOTODIODES TO HARSH CHEMICALS

Photodiode packages and/or operation may be impaired if exposed to CHLOROTHENE, THINNER, ACETONE, or TRICHLOROETHYLENE.

INSTALL WITH CARE

Most photodiodes in this catalog are provided with wire or pin leads for installation in circuit boards or sockets. Observe the soldering temperatures and conditions specified below:

Soldering Iron:	Soldering 30 W or less Temperature at tip of iron 300°C or lower.
Dip Soldering:	Bath Temperature: 260±5°C. Immersion Time: within 5 Sec. Soldering Time: within 3 Sec.
Vapor Phase Soldering:	DO NOT USE
Reflow Soldering:	DO NOT USE

Photodiodes in plastic packages should be given special care. Clear plastic packages are more sensitive to environmental stress than those of black plastic. Storing devices in high humidity can present problems when soldering. Since the rapid heating during soldering stresses the wire bonds and can cause wire to bonding pad separation, it is recommended that devices in plastic packages to be baked for 24 hours at 85°C.

The leads on the photodiode **SHOULD NOT BE FORMED**. If your application requires lead spacing modification, please contact OSI Optoelectronics Applications group at (310)978-0516 before forming a product's leads. Product warranties could be voided.



*Most of our standard catalog products are RoHS Compliant. Please contact us for details

Mechanical Drawings

Mechanical Specifications and Die Topography

1. Parameter Definitions:

A = Distance from top of chip to top of glass.

a = Photodiode Anode.

B = Distance from top of glass to bottom of case.

c = Photodiode Cathode

(Note: cathode is common to case in metal package products unless otherwise noted).

W = Window Diameter.

F.O.V. = Filed of View (see definition below).

2. Dimensions are in inches (1 inch = 25.4 mm).

3. Pin diameters are 0.018 ± 0.002 " unless otherwise specified.

4. Tolerances (unless otherwise noted)

General: $0.XX \pm 0.01$ "

$0.XXX \pm 0.005$ "

Chip Centering: ± 0.010 "

Dimension 'A': ± 0.015 "

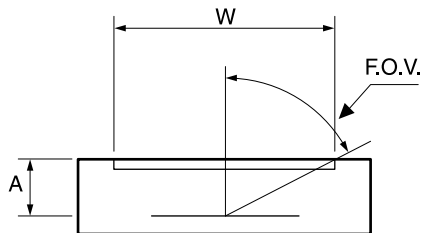
5. Windows

All '**UV**' Enhanced products are provided with QUARTZ glass windows, 0.027 ± 0.002 " thick.

All '**XUV**' products are provided with removable windows.

All '**DLS**' PSD products are provided with A/R coated glass windows.

All '**FIL**' photoconductive and photovoltaic products are epoxy filled instead of glass windows.



$$F.O.V. = \tan^{-1} \left(\frac{W}{2A} \right)$$

For Further Assistance
Please Call One of Our Experienced
Sales and Applications Engineers

310-978-0516

OSI Optoelectronics
An OSI Systems Company

- Or -

visit our website at

www.osioptoelectronics.com

Mechanical Specifications

All units in inches. Pinouts are bottom view.

40 TO-18 41 TO-5 42 TO-8

Products:
SPOT-2DMI

Pin Circle Dia.=0.100

Products:
SC-4D
SL3-1
SPOT-2D
SPOT-3D
SPOT-4D
SPOT-4DMI
QD7-0

Pin Circle Dia.=0.200

Dimensions			
P/N	A	B	W
SC-4D	0.071	0.142	0.240
SL3-1	0.106	0.195	0.217
SPOT-2D	0.063	0.114	0.240
SPOT-3D	0.104	0.138	0.240
SPOT-4D	0.063	0.142	0.240
SPOT-4DMI	0.063	0.142	0.240
SPOT-4DUV	0.063	0.142	0.240
QD7-0	0.050	0.130	0.230

Pinouts					
P/N	1	2	3	4	5
SC-4D	c	c	c	c	a
SL3-1	a	c	a	--	--
SPOT-2D	a	c	a	--	--
SPOT-3D	a	c	a	--	--
SPOT-4D	a	a	a	a	c
SPOT-4DMI	a	a	a	a	c
SPOT-4DUV	a	a	a	a	c
QD7-0	a	a	a	a	c

Products:
SL5-1

Pin Circle Dia.=0.300

43 Low Profile

Products:
SPOT-9D
SPOT-9DMI

Pin Circle Dia.=0.730

44 Special

Products:
SC-10D

Pin Circle Dia.=0.730

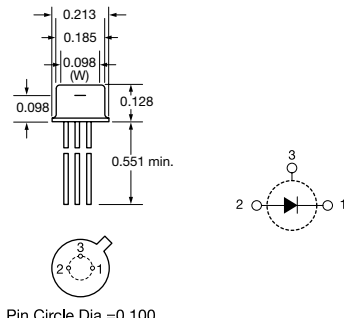
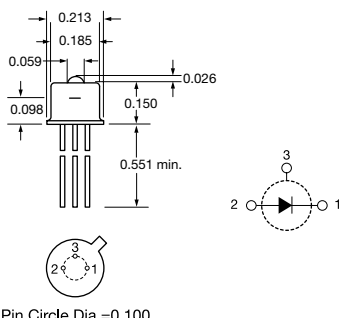
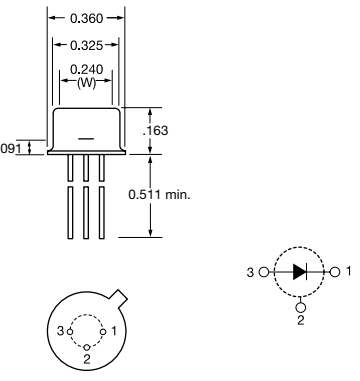
45 Special

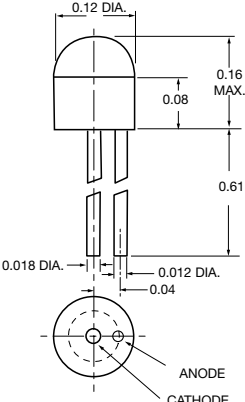
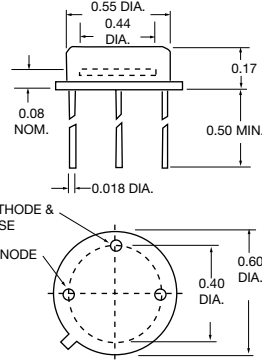
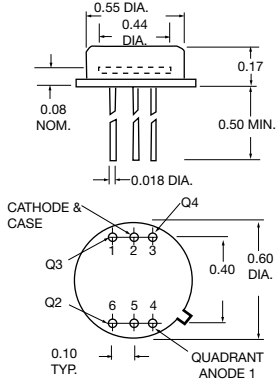
Products:
SC-25D

Pin Circle Dia.=0.950

Mechanical Specifications

All units in inches. Pinouts are bottom view.

65 TO-52	66 TO-52L	67 TO-5
<p>Products: APD02-8-150-T52 APD05-8-150-T52 APD10-8-150-T52</p>  <p>Pin Circle Dia.=0.100</p>	<p>Products: APD02-8-150-T52L APD05-8-150-T52L APD10-8-150-T52L</p>  <p>Pin Circle Dia.=0.100</p>	<p>Products: APD15-8-150-T05 APD30-8-150-T05</p>  <p>Pin Circle Dia.=0.200</p>

68 Plastic	69 TO-8	70 TO-8
<p>Products: CD-1705</p>  <p>ANODE CATHODE</p>	<p>Products: OSD60-0 OSD60-ST OSD60-E</p>  <p>CATHODE & CASE ANODE</p>	<p>Products: QD50-0</p>  <p>CATHODE & CASE Q4 Q3 Q2 Q1 6 5 4 QUADRANT ANODE 1</p>